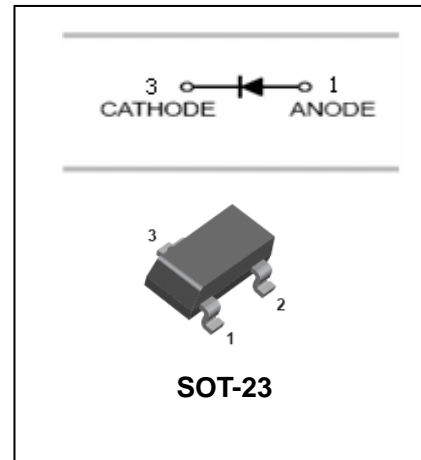


## Surface mount switching diode

## 1SS193

### FEATURES

- Low forward voltage  
 $V_{F(3)}=0.9V(\text{typ})$ .
- Fast switching.
- Fast reverse recovery time:  $t_{rr}=1.6ns(\text{typ})$



### APPLICATIONS

- High speed switching application.

### ORDERING INFORMATION

Type No.	Marking	Package Code
1SS193	F3	SOT-23

### MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Limits	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	85	V
DC Reverse Voltage	$V_R$	80	V
Forward Current(max)	$I_{FM}$	300	mA
Forward Output current	$I_o$	100	mA
Power Dissipation	$P_d$	150	mW
Operating Junction Temperature Range	$T_j$	125	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-55 to +125	$^\circ\text{C}$

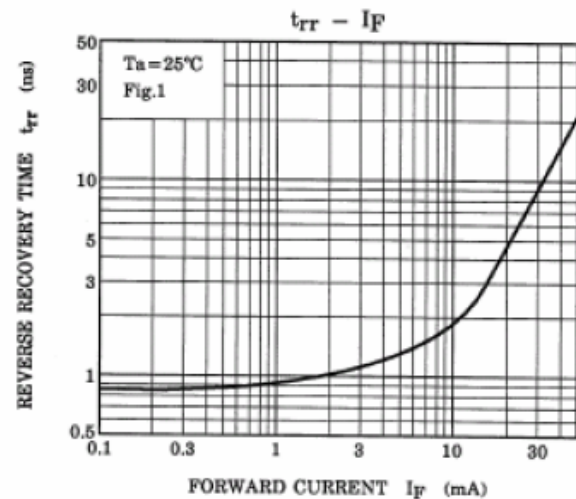
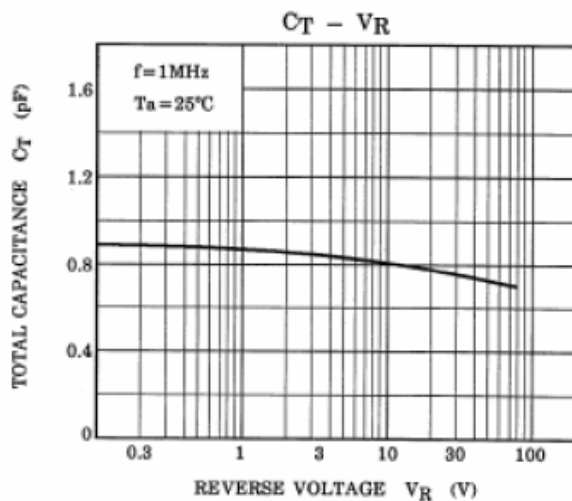
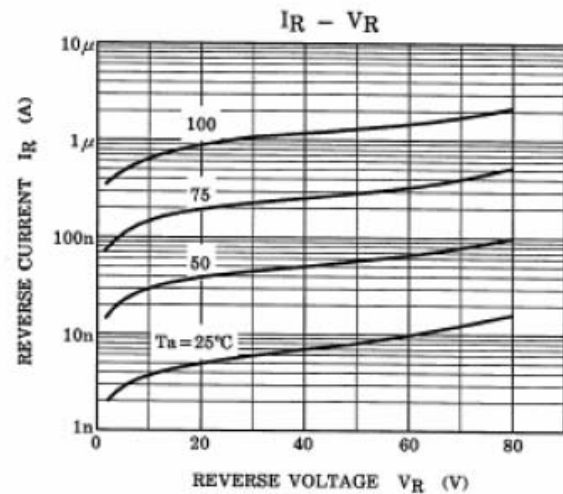
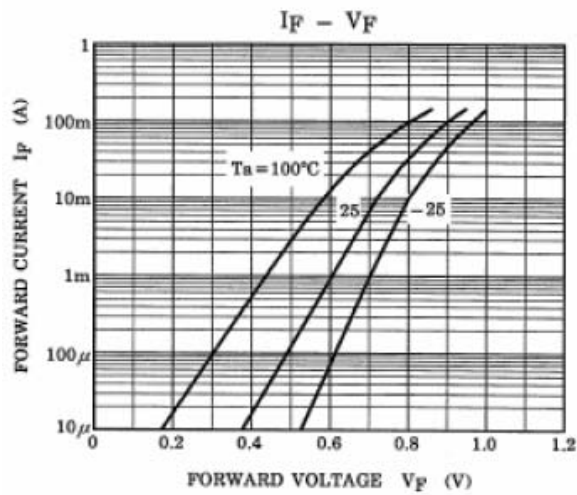
### ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	MAX	UNIT	Test Condition
Reverse Breakdown Voltage	$V_{(BR)R}$	80	-	-	V	$I_R=100\mu\text{A}$
Forward Voltage	$V_F$	-	0.60 0.72 0.90	1.2	V	$I_F=1\text{mA}$ $I_F=10\text{mA}$ $I_F=100\text{mA}$
Reverse Leakage Current	$I_R$	-		0.1 0.5	$\mu\text{A}$	$V_R=30\text{V}$ $V_R=80\text{V}$
Junction Capacitance	$C_j$	-	0.90	3.0	pF	$V_R=0\text{V}, f=1.0\text{MHz}$
Reverse Recovery Time	$t_{rr}$	-	1.6	4.0	ns	$I_F=I_R=10\text{mA}, I_{rr}=0.1*I_R$

## Surface mount switching diode

**1SS193**

TYPICAL CHARACTERISTICS @  $T_a=25^\circ\text{C}$  unless otherwise specified



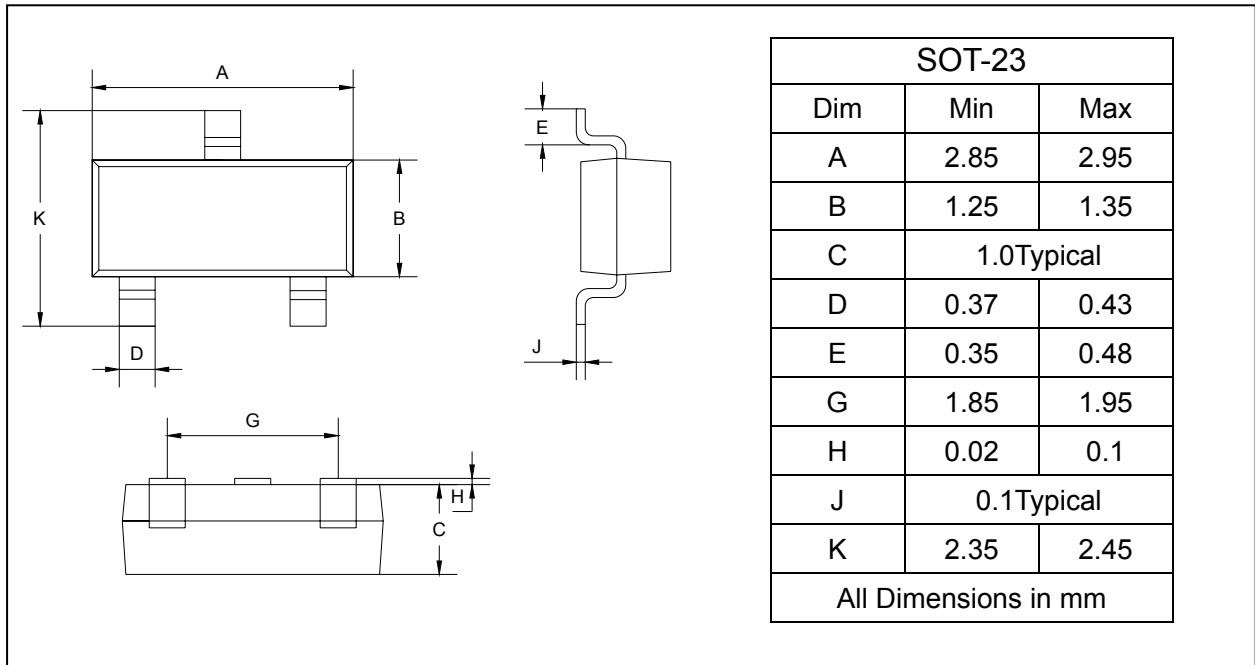
## Surface mount switching diode

## 1SS193

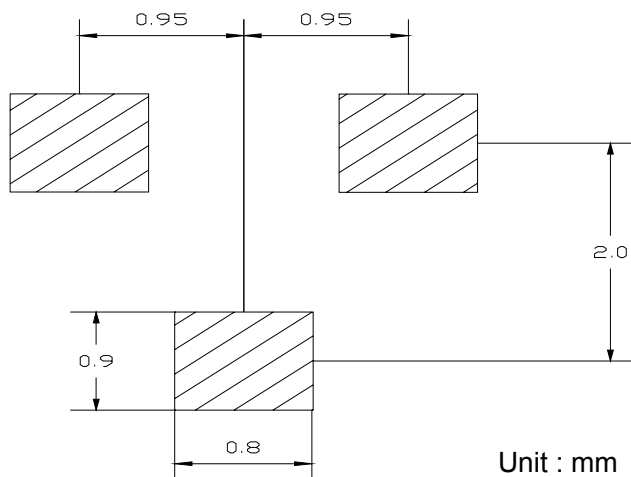
### PACKAGE OUTLINE

Plastic surface mounted package

SOT-23



### SOLDERING FOOTPRINT



### PACKAGE INFORMATION

Device	Package	Shipping
1SS193	SOT-23	3000/Tape&Reel